



High-end Power Semiconductor Manufacturer

# ZK800A 1100-2000V

## Fast Recovery Diode

- Low switching losses
- Low reverse recovery charge
- High power cycling capability



Average forward current		$I_{FAV}$		850 A		
Repetitive peak reverse voltage		$V_{RRM}$		1100 – 2000 V		
Reverse recovery time		$t_{rr}$		3.00 $\mu$ s		
$V_{RRM}$ , V	1100	1200	1400	1600	1800	2000
Voltage code	11	12	14	16	18	20
$T_j$ , °C	– 60 – 150					

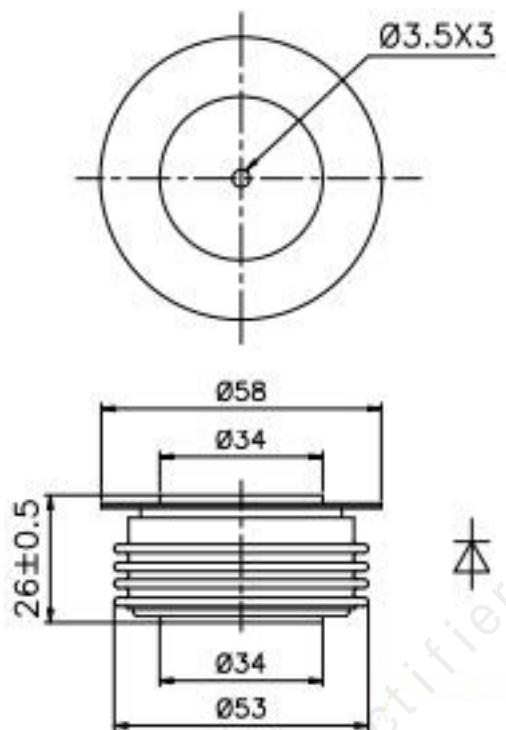
### MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
<b>ON-STATE</b>					
$I_{FAV}$	Average forward current	A	850	$T_c=85$ °C; Double side cooled; 180° half-sine wave; 50 Hz	
$I_{FSM}$	Surge forward current	kA	12.0	$T_j=T_{j\max}$	180° half-sine wave; $t_p=10$ ms; $V_R=0.6V_{RRM}$
$I^2t$	Safety factor	$A^2s \cdot 10^3$	720	$T_j=T_{j\max}$	180° half-sine wave; $t_p=10$ ms; $V_R=0.6V_{RRM}$
<b>BLOCKING</b>					
$V_{RRM}$	Repetitive peak reverse voltages	V	1100–2000	$t_p=10$ ms	
$V_R$	Reverse continuous voltages	V	$0.6 \cdot V_{RRM}$	$T_j=T_{j\max}$ ;	
<b>THERMAL</b>					
$T_{stg}$	Storage temperature	°C	–40–160		
$T_j$	Operating junction temperature	°C	–60 –150		
<b>MECHANICAL</b>					
F	Mounting force	kN	10 – 20		

## CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
<b>ON-STATE</b>					
V <sub>FM</sub>	Peak forward voltage, max	V	2.80	T <sub>j</sub> =25 °C; I <sub>TM</sub> =2400A, F=15.0kN	
V <sub>F(TO)</sub>	Forward threshold voltage, max	V	1.51	T <sub>j</sub> =T <sub>j max</sub> ;	
r <sub>F</sub>	Forward slope resistance, max	mΩ	0.37		
<b>BLOCKING</b>					
I <sub>RRM</sub>	Repetitive peak reverse current, max	mA	50	T <sub>j</sub> =T <sub>j max</sub> ; V <sub>R</sub> =V <sub>RRM</sub>	
<b>SWITCHING</b>					
Q <sub>rr</sub>	Total recovered charge, max	µC	130	I <sub>TM</sub> =1000A, t <sub>p</sub> =2000µs, -di/dt=60A/µs, V <sub>R</sub> =50V	
t <sub>rr</sub>	Reverse recovery time <sup>1)</sup> , max	µs	3.00		
<b>THERMAL</b>					
R <sub>thjc</sub>	Thermal resistance, junction to case, max	°C/W	0.0350	Clamping force 15.0kN	Double side cooled
R <sub>thck</sub>	Thermal resistance, case to heatsink, max	°C/W	0.0080	Clamping force 15.0kN	Double side cooled
<b>MECHANICAL</b>					
w	Weight, max	g	250		

## OVERALL DIMENSIONS



ZT40

All dimensions in millimeters